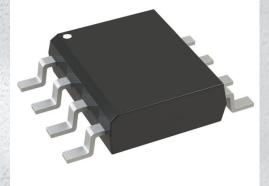


DMP2040USS-13 Datasheet

www.digi-electronics.com

Man



DiGi Electronics Part Number	DMP2040USS-13-DG
Manufacturer	Diodes Incorporated
Aanufacturer Product Number	DMP2040USS-13
Description	MOSFET P-CH 20V 7A/15A 8SO T&R 2
Detailed Description	P-Channel 20 V 7A (Ta), 15A (Tc) 800mW (Ta) Surfa ce Mount 8-SO

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMP2040USS-13	Diodes Incorporated
Series:	Product Status:
-	Active
FET Type:	Technology:
P-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
20 V	7A (Ta), 15A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
2.5V, 4.5V	33mOhm @ 8.9A, 4.5V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
1.5V @ 250µA	19 nC @ 8 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±12V	834 pF @ 10 V
FET Feature:	Power Dissipation (Max):
-	800mW (Ta)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
8-SO	8-SOIC (0.154", 3.90mm Width)
Base Product Number:	
DMP2040	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	





Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
-20V	$33m\Omega @ V_{GS} = -4.5V$	-7.0A
-200	$52m\Omega @ V_{GS} = -2.5V$	-5.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

Case: SO-8

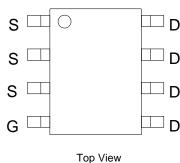
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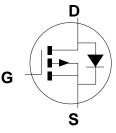
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- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072g (Approximate)







Equivalent Circuit

Ordering Information (Note 4)

Top View

Part Number	Case	Packaging
DMP2040USS-13	SO-8	2500/Tape & Reel

Pin-Out

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

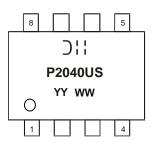
and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



) | | = Manufacturer's Marking P2040US = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 19 = 2019) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±12	V
	Steady	T _A = +25°C	- I _D	-7.0	А
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$	State	T _A = +70°C		-5.5	
	Steady State	$T_{C} = +25^{\circ}C$	Ι _D	-15	А
Continuous Drain Current (Note 7) $V_{GS} = -4.5V$		T _C = +70°C		-12	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-30	А
Continuous Source-Drain Diode Current (Note 6)			I _S	-2.2	А
Avalanche Current (Note 8) L = 0.1mH			I _{AS}	-16	А
Avalanche Energy (Note 8) L = 0.1mH			E _{AS}	13.5	mJ

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	91	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	64	°C/W
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _{0JC}	13.5	°C/W
Operating and Storage Temperature Range	·	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						•
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	—	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V _{GS(TH)}	-0.6	—	-1.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Deserve	_	26	33	mΩ	$V_{GS} = -4.5V, I_D = -8.9A$
Static Dram-Source On-Resistance	R _{DS(ON)}	_	37.5	52	11122	$V_{GS} = -2.5V, I_D = -6.9A$
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -2.9A$
DYNAMIC CHARACTERISTICS (Note 10)						-
Input Capacitance	Ciss	_	834	—		V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	Coss	—	133	—	pF	
Reverse Transfer Capacitance	C _{rss}	_	105	—		
Gate Resistance	Rg	_	4.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	8.6	—		
Total Gate Charge (V _{GS} = -8V)	Qg	_	19	—	nC	$V_{DS} = -6V, I_D = -8.9A$
Gate-Source Charge	Q _{gs}	_	1.5	—		
Gate-Drain Charge	Q _{gd}	_	2.5	—		
Turn-On Delay Time	t _{D(ON)}	_	5.8	—		
Turn-On Rise Time	t _R	_	7.7	_		$V_{DD} = -6V, R_L = 6\Omega$
Turn-Off Delay Time	t _{D(OFF)}	_	28.1	_	ns	$V_{GS} = -4.5V, R_g = 6\Omega, I_D = -1A$
Turn-Off Fall Time	tF	_	14.6	_		
Body Diode Reverse Recovery Time	t _{RR}		9.8	—	ns	I _F = -8.9A, di/dt = -100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}		2.7	_	nC	I _F = -8.9A, di/dt = -100A/µs

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

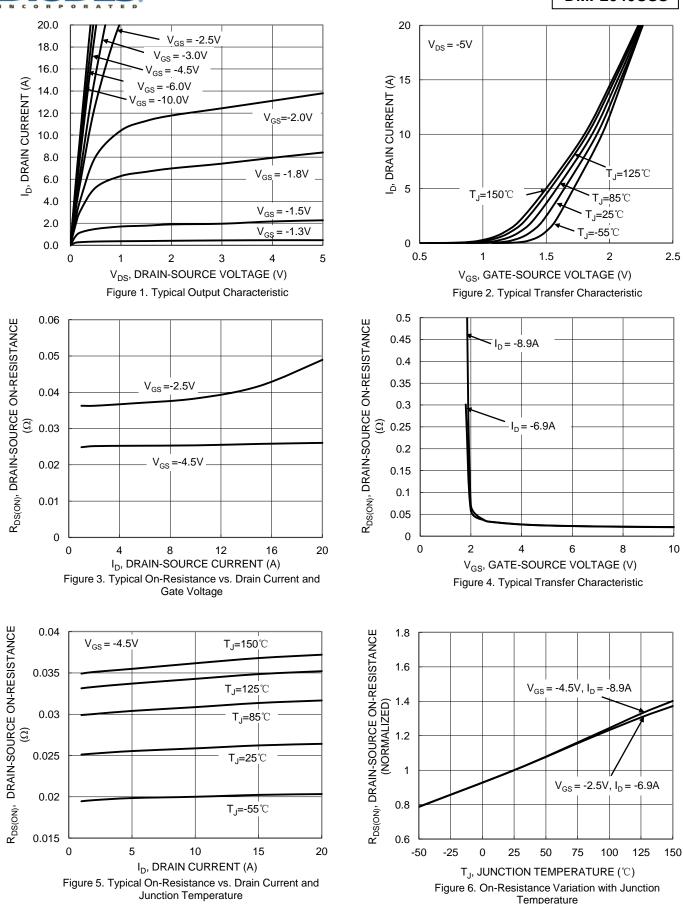
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.

DMP2040USS-13 Diodes Incorporated MOSFET P-CH 20V 7A/15A 8SO T&R 2



DMP2040USS





 $I_D = -1mA$

75

100

125

150

 $I_{D} = -250 \mu A$

0

25

50

C_{iss}

Coss

C_{rss}

10

15

, =100µs

P

w 0s

DC

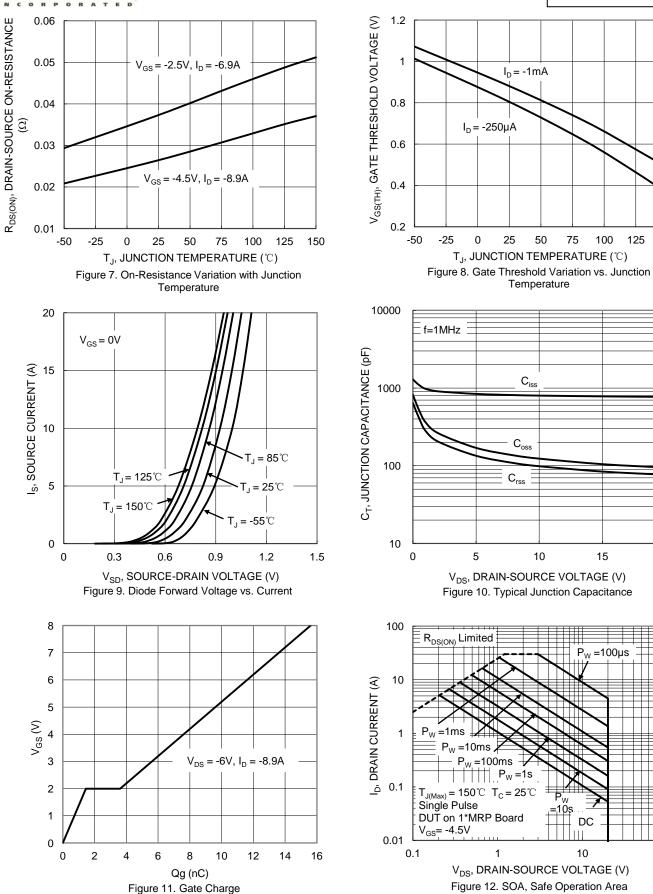
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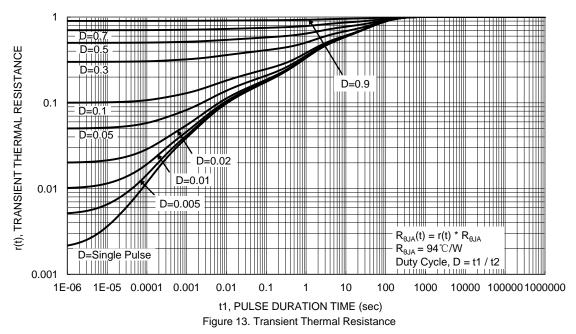
P_w=1s

1



100



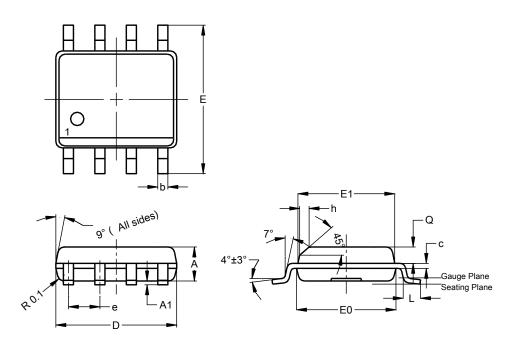




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

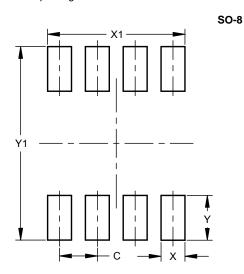
SO-8



SO-8					
Dim	Min	Max	Тур.		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
c	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
e		-	1.27		
h			0.35		
1	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All	Dimens	sions in	mm		

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



 Dimensions
 Value (in mm)

 C
 1.27

 X
 0.802

 X1
 4.612

 Y
 1.505

 Y1
 6.50

DMP2040USS
Document number: DS40054 Rev. 4 - 2



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